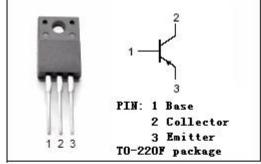


# isc Silicon PNP Power Transistor

### **DESCRIPTION**

- · Collector-Emitter Breakdown Voltage-
  - : V<sub>(BR)CEO</sub>= -80V(Min)
- · Collector Power Dissipation-
- : Pc= 25W@ Tc= 25℃
- · Low Collector Saturation Voltage-
  - :  $V_{CE(sat)} = -1.7V(Max)@ (I_C = -3A, I_B = -0.3A)$
- Complement to Type 2SD2060
- Minimum Lot-to-Lot variations for robust device performance and reliable operation



### **APPLICATIONS**

• Designed for general purpose applications.

### ABSOLUTE MAXIMUM RATINGS(Ta=25℃)

SYMBOL	PARAMETER	VALUE	UNIT
V <sub>CBO</sub>	Collector-Base Voltage	-80	V
V <sub>CEO</sub>	Collector-Emitter Voltage	-80	V
V <sub>EBO</sub>	Emitter-Base Voltage	-5	V
Ic	Collector Current-Continuous	-4	А
I <sub>B</sub>	Base Current-Continuous	-0.4	А
Pc	Collector Power Dissipation @T <sub>C</sub> =25°C	25	W
TJ	Junction Temperature	150	$^{\circ}$
T <sub>stg</sub>	Storage Temperature	-55~150	$^{\circ}$

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L - ( - ( ) ( )	H K	- R	;- L	],
D		J		
N		m	m	
	DIM	MIN	MAX	
3	A	14.95	15.05	
1	В	10.00	10.10	
1	С	4.40	4.60	
B.	D	0.75	0.90	
	F	3.10	3.30	
9	H	3.70	3.90	
9	J	0.50	0.70	
2	K	13.4	13.6	
1	L	1.10	1.30	
1	N	5.00	5.20	
9	Q	2.70	2.90	
4	R	2.20	2.40	
8)	S	2.65 6.40	2.85 6.60	
	U	17 (4.1)	0.00	



## isc Silicon PNP Power Transistor

2SB1368

### **ELECTRICAL CHARACTERISTICS**

Tj=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
V <sub>(BR)CEO</sub>	Collector-Emitter Breakdown Voltage	I <sub>C</sub> = -50mA; I <sub>B</sub> = 0	-80			V
V <sub>CE(sat)</sub>	Collector-Emitter Saturation Voltage	I <sub>C</sub> = -3A; I <sub>B</sub> = -0.3A			-1.7	V
V <sub>BE</sub> (on)	Base-Emitter On Voltage	I <sub>C</sub> = -3A; V <sub>CE</sub> = -5V			-1.5	V
I <sub>CBO</sub>	Collector Cutoff Current	V <sub>CB</sub> = -80V; I <sub>E</sub> = 0			-30	μА
I <sub>EBO</sub>	Emitter Cutoff Current	V <sub>EB</sub> = -5V; I <sub>C</sub> = 0			-100	μА
h <sub>FE-1</sub>	DC Current Gain	I <sub>C</sub> = -0.5A; V <sub>CE</sub> = -5V	40		240	
h <sub>FE-2</sub>	DC Current Gain	I <sub>C</sub> = -3A; V <sub>CE</sub> = -5V	15			

### h<sub>FE-1</sub> Classifications

R	0	Y
40-80	70-140	120-240

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